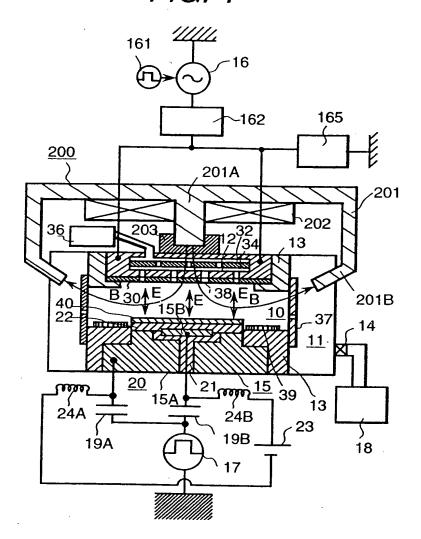
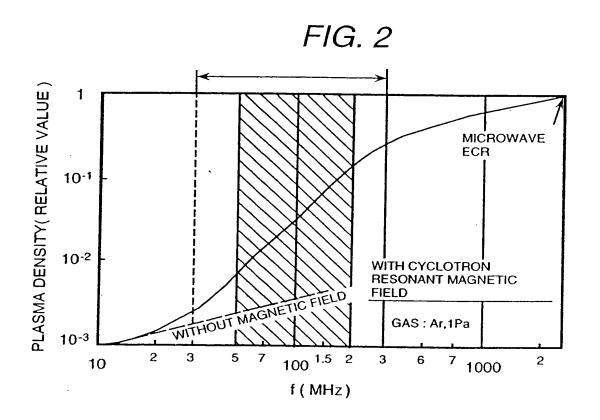
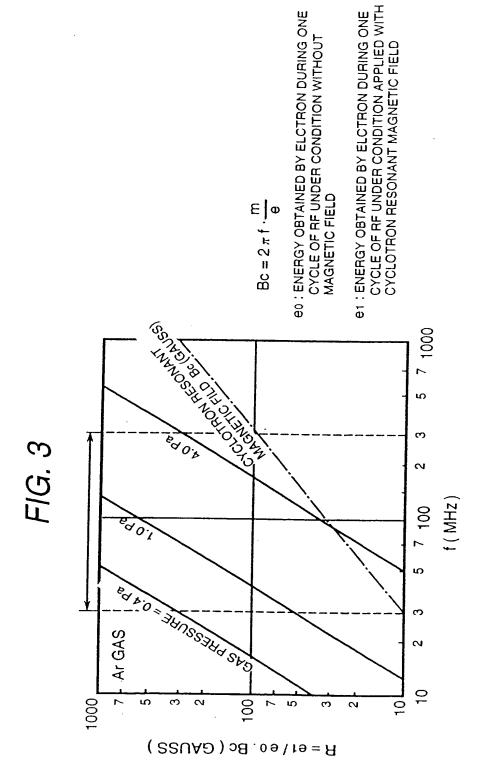
FIG. 1









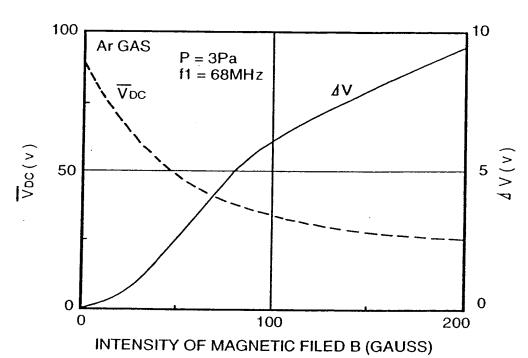
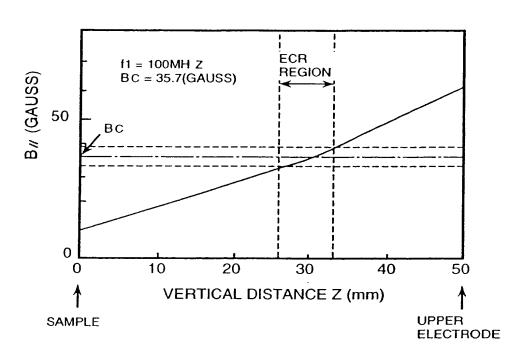
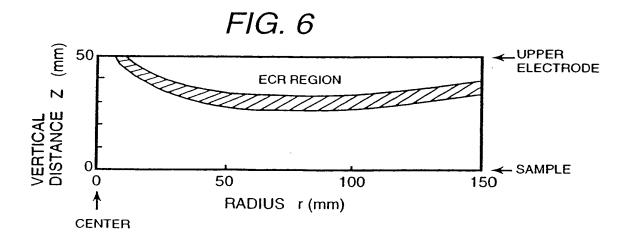
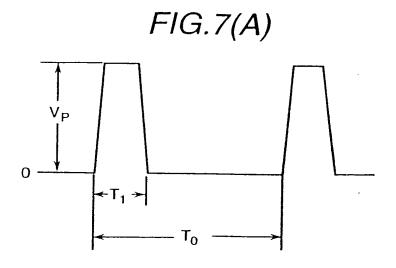
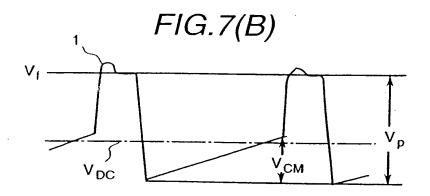


FIG. 5









$$V_{CM} = \frac{q}{c} = \frac{i_i \cdot (T_0 - T_1)}{(\epsilon_{\gamma} \epsilon_0 / d) \times K}$$

 i_i : ION CURRENT DENSITY

 $\varepsilon_{-\gamma}$: SPECIFIC DIELECTRIC CONSTANT OF

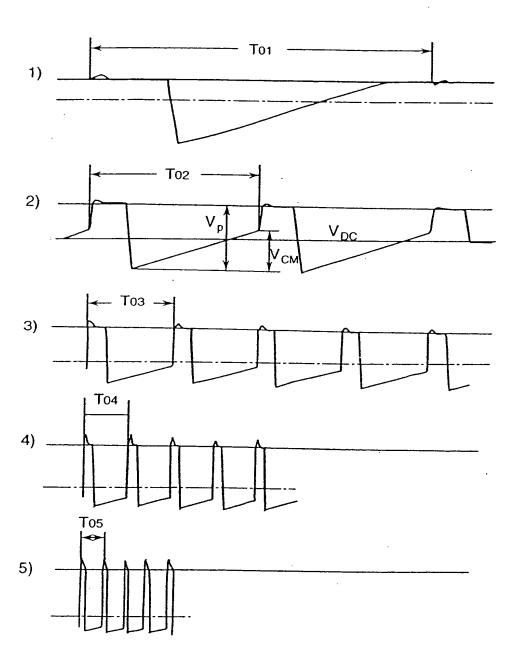
ELECTROSTATIC ATTRACTING FILM

d: THICKNESS OF ELECTROSTATIC

ATTRACTING FILM

K: ELECTRODE COVERING RATIO OF ELECTROSTATIC ATTRACTING FILM

FIG. 8



To1: To2: To3: To4: To5 = 16:8:4:2:1

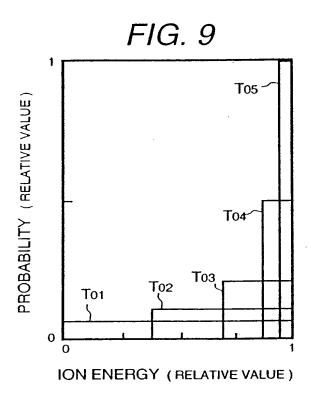
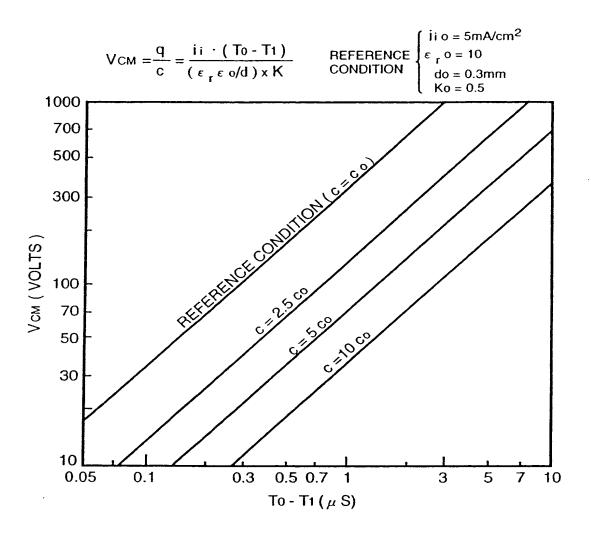
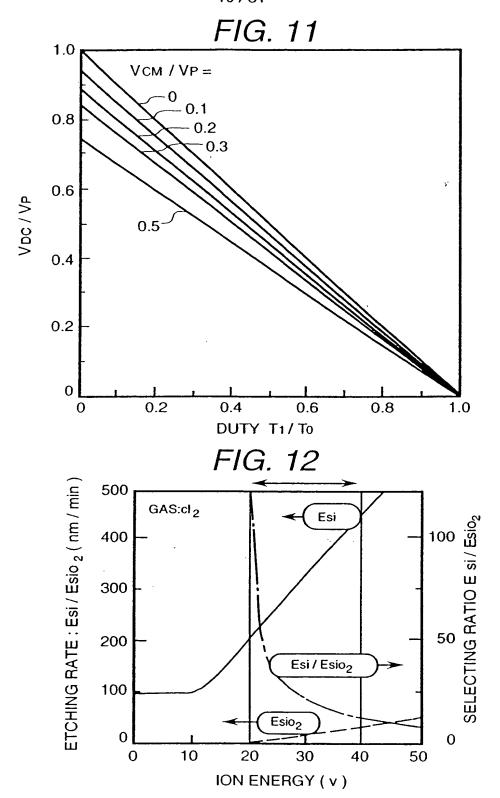


FIG. 10





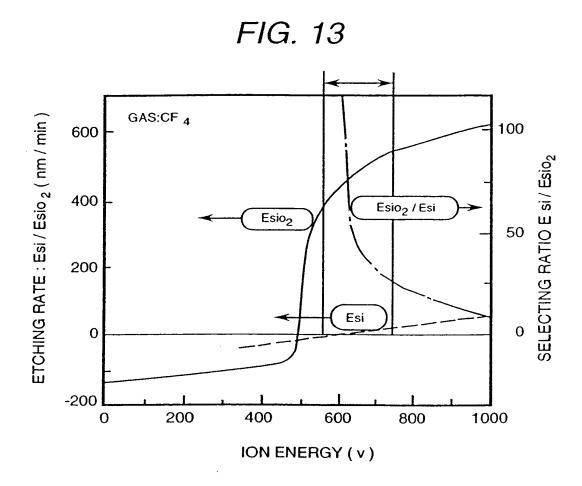


FIG. 14

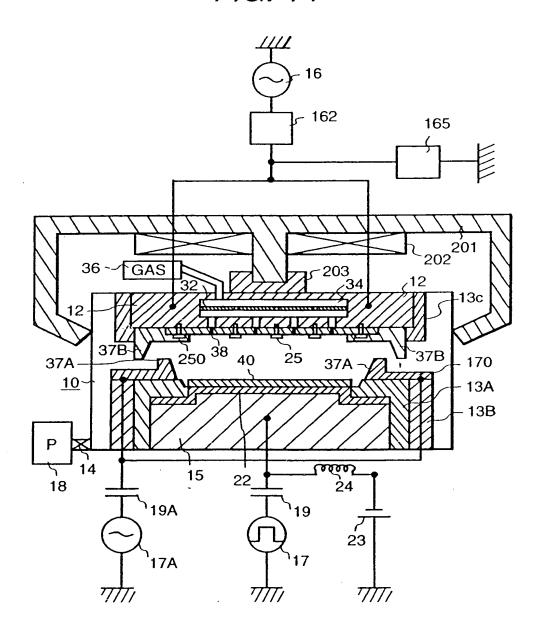


FIG. 15

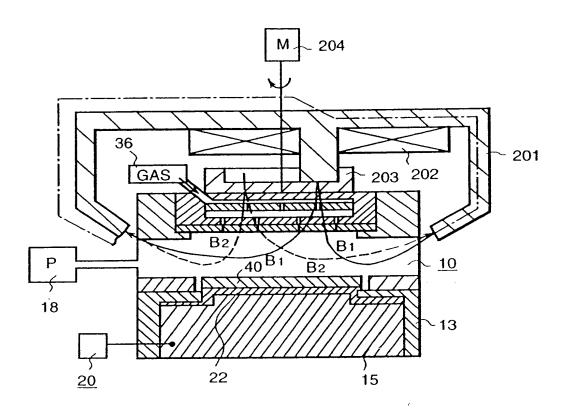


FIG. 16

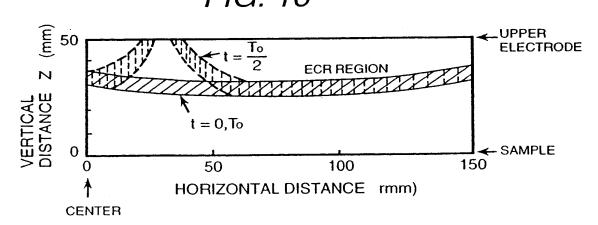


FIG. 18

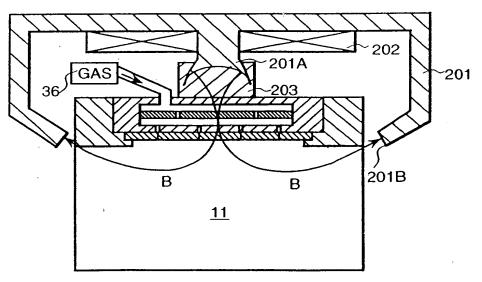


FIG. 19

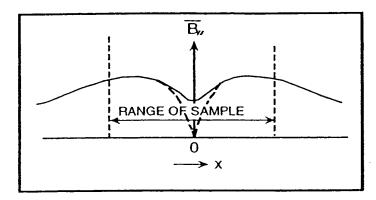
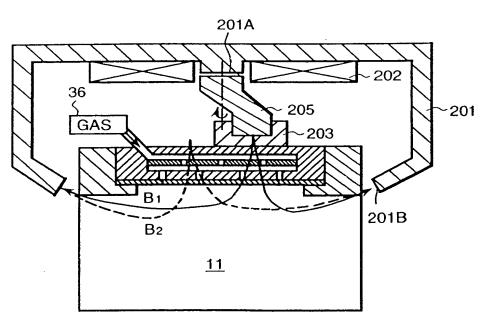


FIG. 20



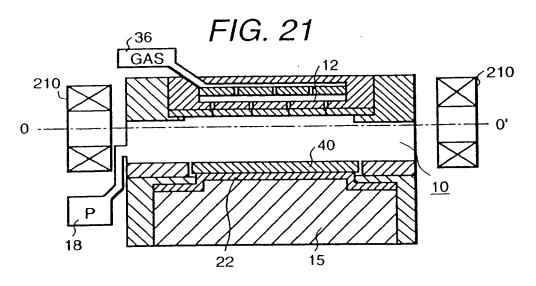


FIG. 22

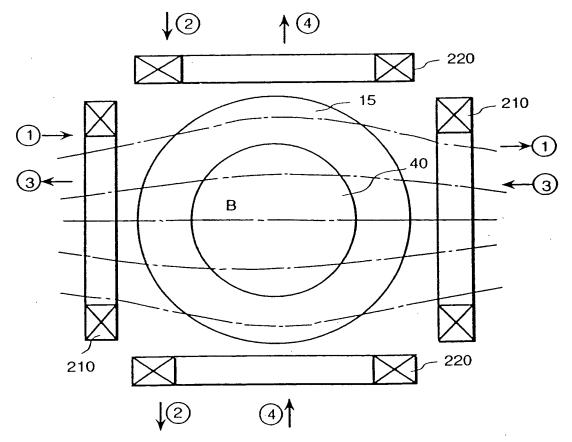


FIG. 23

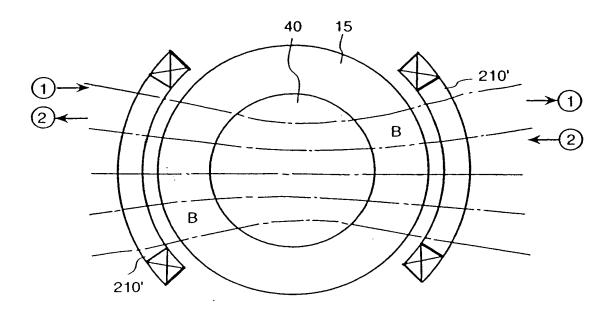


FIG. 24

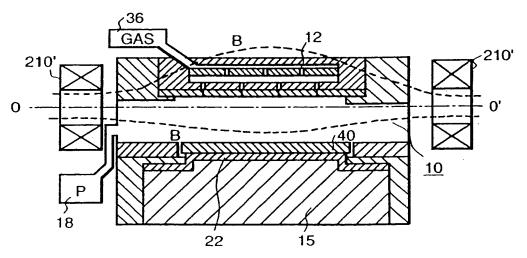


FIG. 25

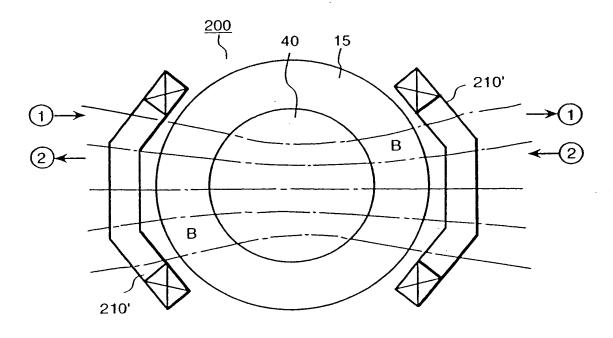


FIG. 26

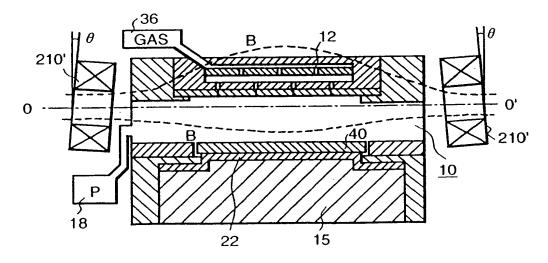


FIG. 27

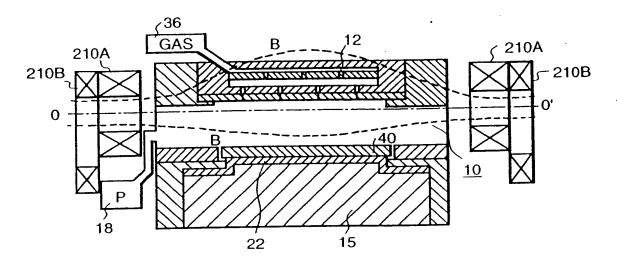


FIG. 28

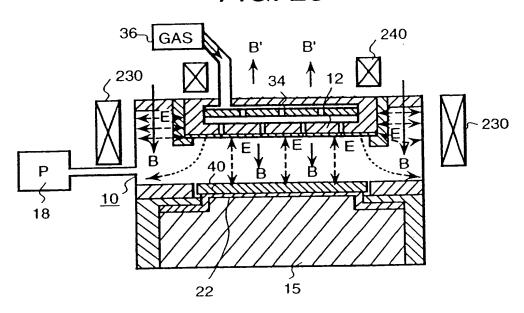


FIG. 29

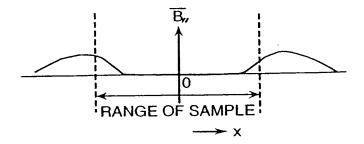


FIG. 30

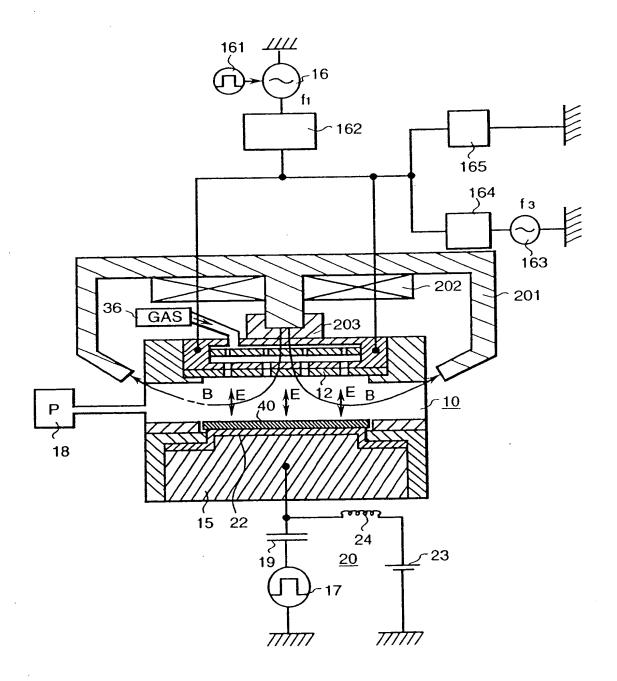


FIG. 31

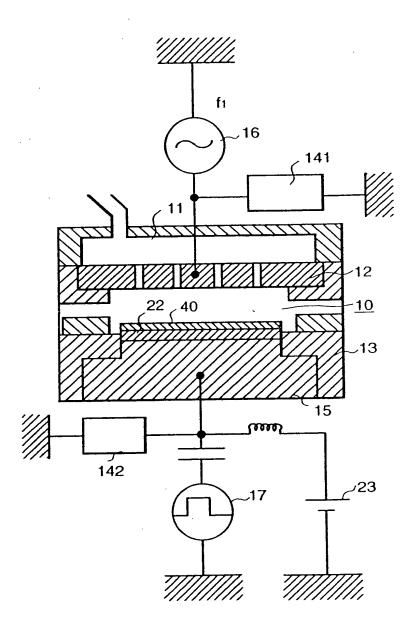
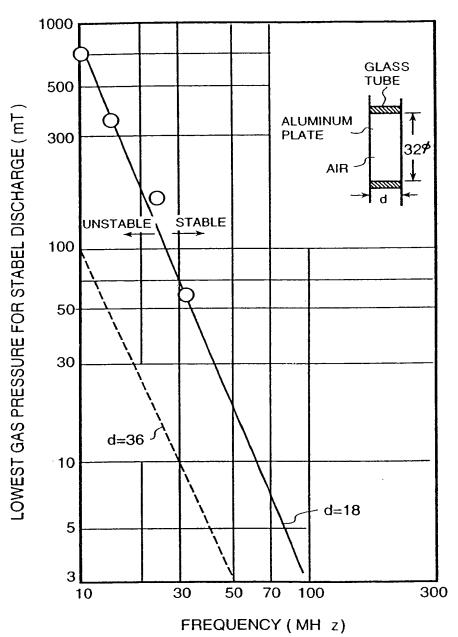


FIG. 32



FREQUENCY-LOWEST GAS PRESSURE FOR STABLE DISCHARGE CHARACTERISTC

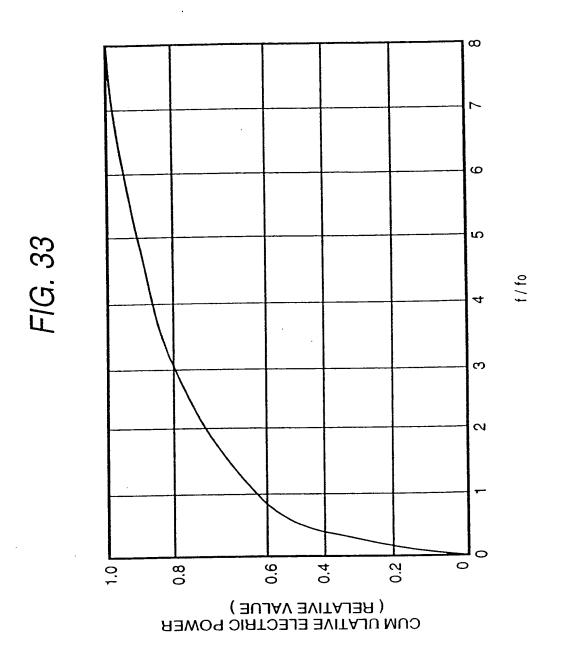


FIG. 34

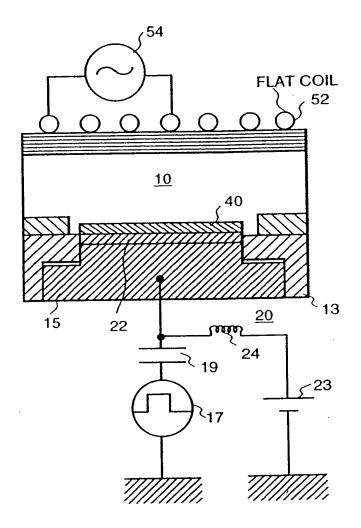


FIG. 35

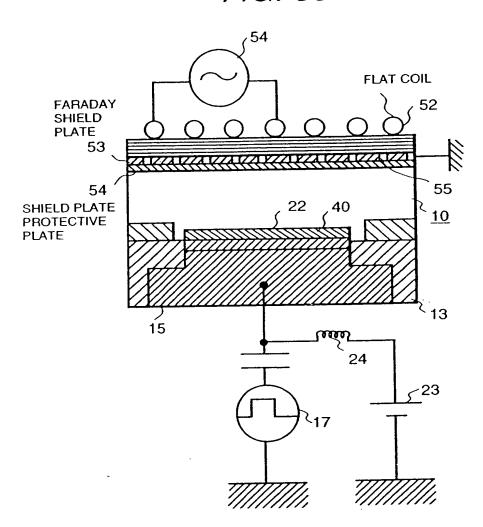


FIG. 36

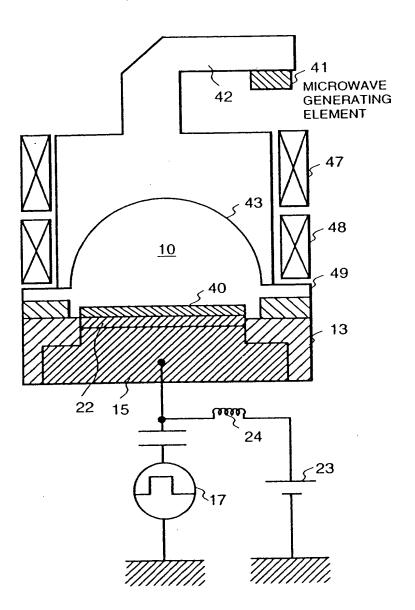
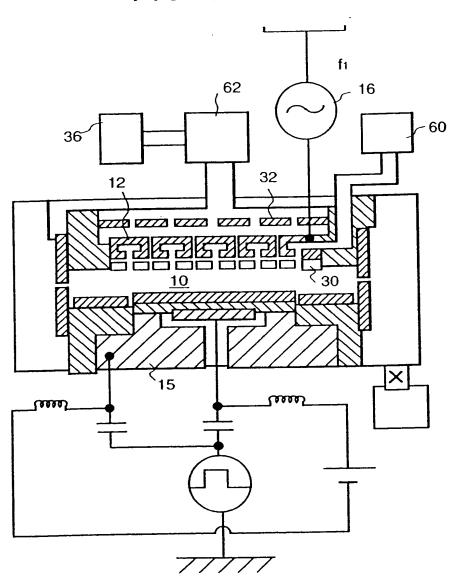


FIG. 37



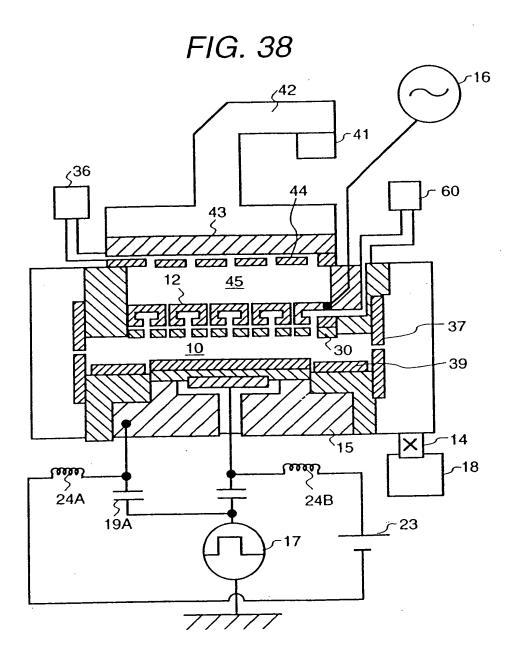


FIG. 39

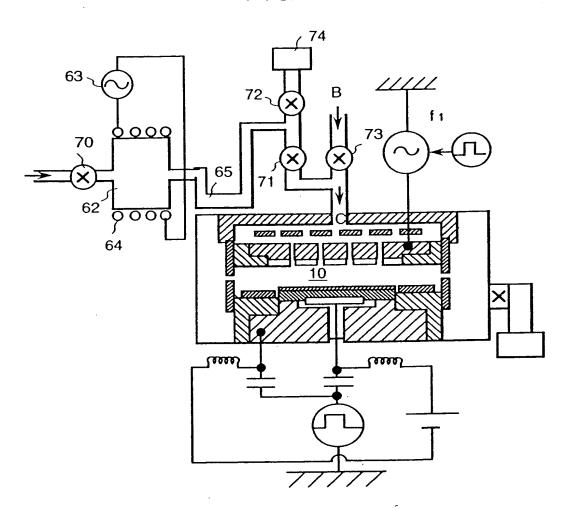


FIG. 40

